

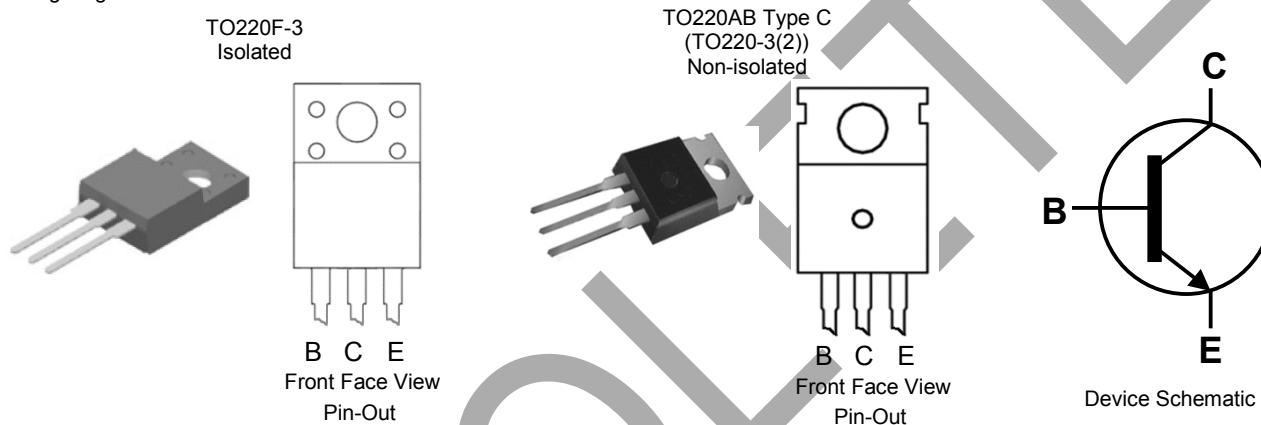
Features

- $BV_{CEO} > 450V$
- $BV_{CES} > 700V$
- $BV_{EBO} > 9V$
- $I_C = 4A$ high Collector Current
- **Lead-Free Finish; RoHS Compliant (Notes 1 & 2)**
- **Halogen and Antimony Free. "Green" Device (Note 3)**

Applications

Low power AC-DC SMPS for:

- Battery Chargers for Mobile Phone / Tablets / Smartphones
- Power Supply for DVD / STB
- LED lighting



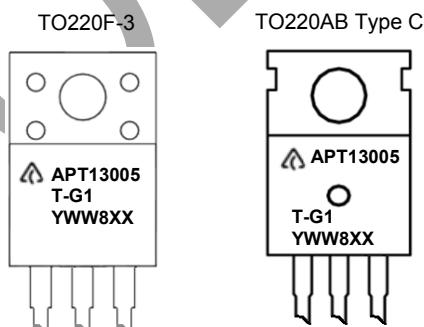
Ordering Information (Note 4)

Product	Package	Marking	Quantity
APT13005TF-G1	TO220F-3	APT13005TF-G1	1,000 per Box in Tubes
APT13005T-G1	TO220AB Type C (TO220-3(2))	APT13005T-G1	1,000 per Box in Tubes

Notes:

1. EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. All applicable RoHS exemptions applied.
2. See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
4. For packaging details, go to our website at <http://www.diodes.com/products/packages.html>.

Marking Information



 = Manufacturers' code marking
 For TO220F-3, APT13005TF-G1 = Product Type Marking ID
 For TO220AB Type C, APT13005T-G1 = Product Type Marking ID
 YWW = Date Code Marking
 e.g. 312 = Year 2013, Week 12.
 8 = Assembly site code
 XX = Batch Number

Absolute Maximum Ratings (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Emitter Voltage	V_{CES}	700	V
Collector-Emitter Voltage	V_{CEO}	450	V
Emitter-Base Voltage	V_{EBO}	9	V
Collector Current	I_C	4	A
Peak Collector Current	I_{CM}	8	A
Base Current	I_B	2	A
Peak Base Current	I_{BM}	4	A

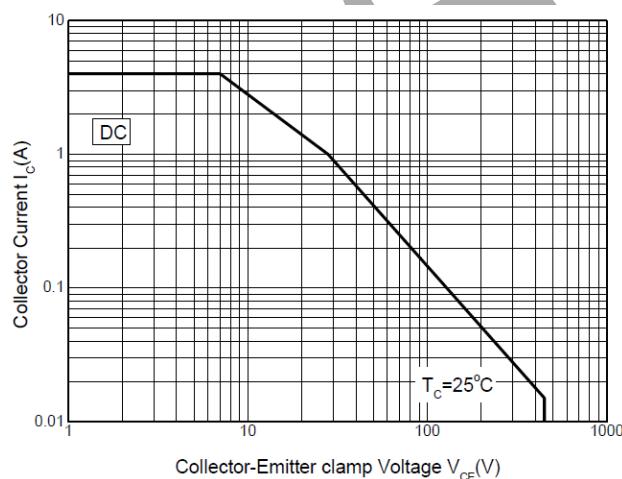
Thermal Characteristics (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Power Dissipation @ $T_C = +25^\circ\text{C}$	P_D	28	W
		75	
Thermal Resistance, Junction to Case	R_{JC}	4.5	°C/W
		1.67	
Operating and Storage Temperature Range	T_J, T_{STG}	-65 to +150	°C

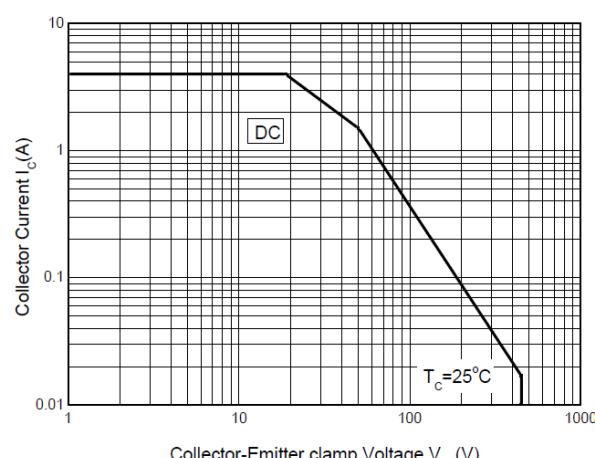
ESD Ratings (Note 6)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	$\geq 8,000$	V	3B
Electrostatic Discharge - Machine Model	ESD MM	≥ 400	V	C

Note: 6. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

Safe Operating Areas (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)


Safe Operating Areas (TO-220F-3 Package)


 Safe Operating Areas
 (TO-220-3/TO-220-3(2) Package)

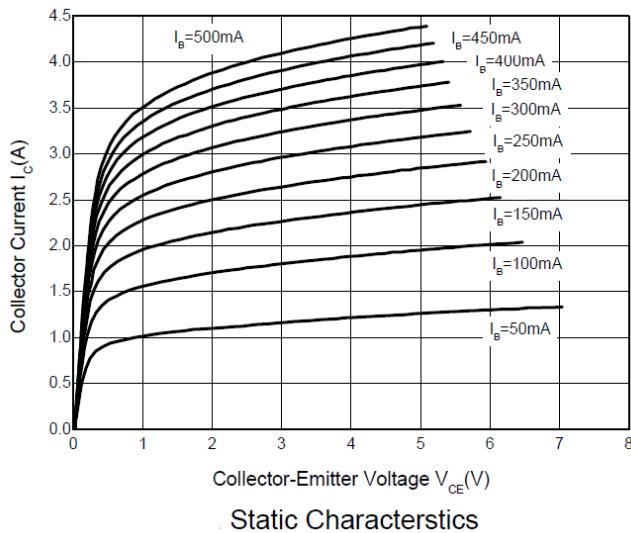
Electrical Characteristics (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)

Characteristic	Symbol	Min	Typ	Max	Unit	Test Condition
Collector-Emitter Breakdown Voltage	BV_{CES}	700	—	—	V	$I_C = 100\mu\text{A}, V_{\text{BE}} = 0\text{V}$
Collector-Emitter Breakdown Voltage	BV_{CEO}	450	—	—	V	$I_C = 100\mu\text{A}$
Emitter-Base Breakdown Voltage	BV_{EBO}	9	—	—	V	$I_E = 100\mu\text{A}$
Collector Cutoff Current	I_{CEV}	—	—	10	μA	$V_{\text{CE}} = 700\text{V}, V_{\text{BE}} = -1.5\text{V}$
DC current transfer Static ratio (Note 5)	h_{FE}	15 8	—	35 35	—	$I_C = 1\text{A}, V_{\text{CE}} = 5\text{V}$ $I_C = 2\text{A}, V_{\text{CE}} = 5\text{V}$
Collector-Emitter Saturation Voltage (Note 5)	$V_{\text{CE}(\text{sat})}$	— — —	— — —	0.3 0.6 0.9	V	$I_C = 1\text{A}, I_B = 0.2\text{A}$ $I_C = 2\text{A}, I_B = 0.5\text{A}$ $I_C = 4\text{A}, I_B = 1\text{A}$
Base-Emitter Saturation Voltage (Note 5)	$V_{\text{BE}(\text{sat})}$	— —	— —	1.1 1.3	V	$I_C = 1\text{A}, I_B = 0.2\text{A}$ $I_C = 2\text{A}, I_B = 0.5\text{A}$
Output Capacitance	C_{ob}	—	45	—	pF	$V_{\text{CB}} = 10\text{V}, f = 0.1\text{MHz}$
Transition Frequency	f_T	4	—	—	MHz	$I_C = 0.5\text{A}, V_{\text{CE}} = 10\text{V}$
Turn-on Time with Resistive Load	t_{on}	—	—	0.8	μs	$I_C = 2\text{A}, V_{\text{CC}} = 125\text{V}$ $I_{B1} = -I_{B2} = 0.4\text{A}$
Storage Time with Resistive Load	t_s	—	—	4.5		
Fall Time with Resistive Load	t_f	—	—	0.9		

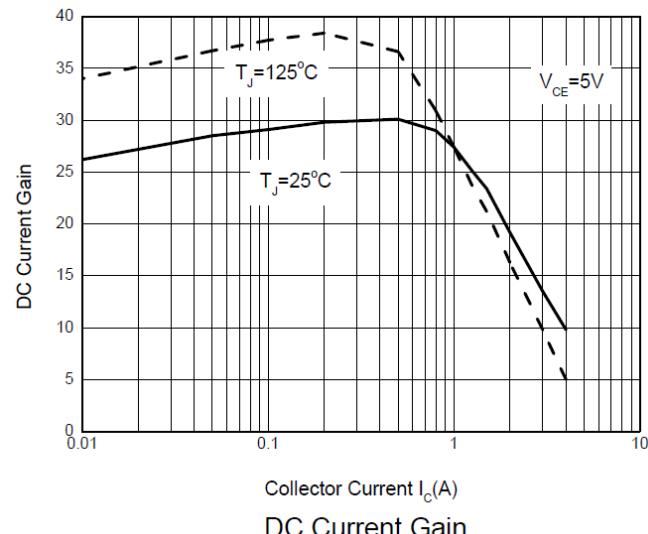
Note: 5. Measured under pulsed conditions. Pulse width $\leq 300\mu\text{s}$. Duty cycle $\leq 2\%$.

OBSOLETE

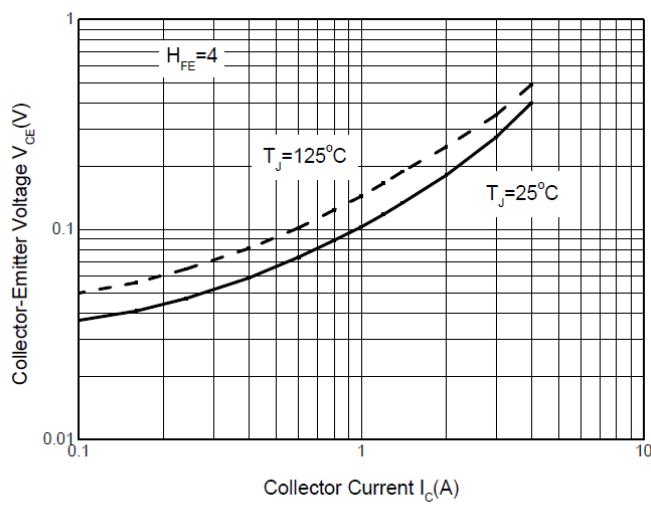
Typical Electrical Characteristics (@ $T_A = +25^\circ\text{C}$, unless otherwise specified.)



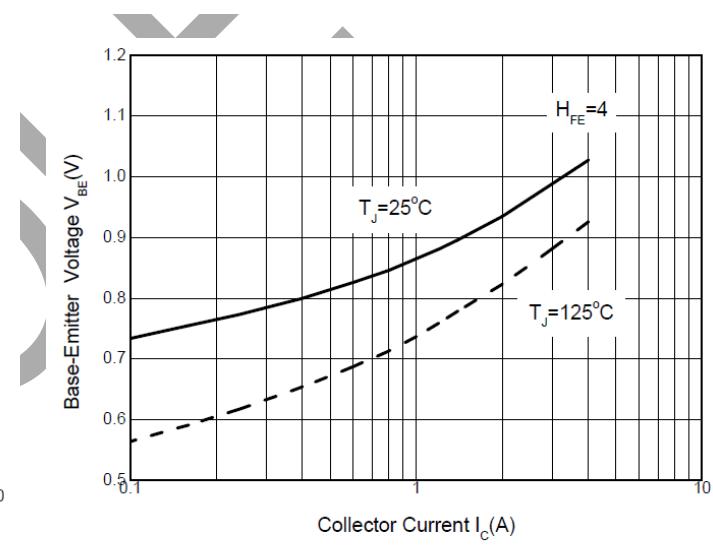
Static Characteristics



DC Current Gain



Collector-Emitter Saturation Region



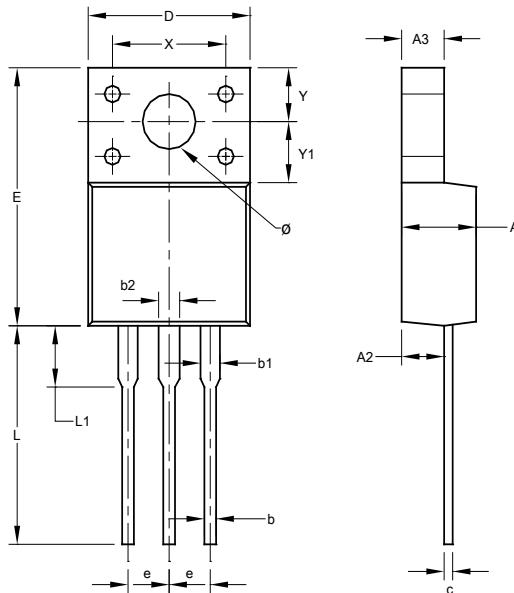
Base-Emitter Saturation Voltage



Package Outline Dimensions

Please see AP02002 at <http://www.diodes.com/datasheets/ap02002.pdf> for latest version.

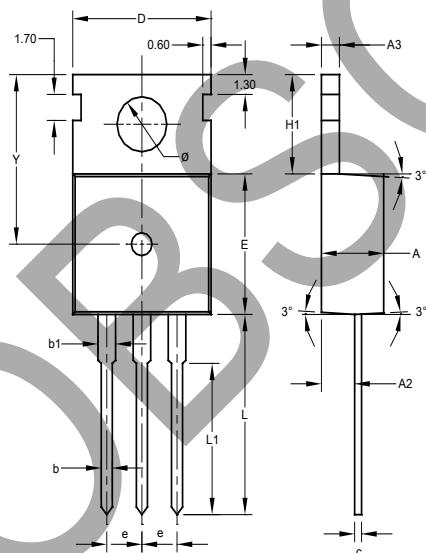
TO220F-3



TO220F-3			
Dim	Min	Max	Typ
A	4.300	4.900	-
A2	2.520	2.920	-
A3	2.350	2.900	-
b	0.550	0.900	-
b1	1.000	1.400	-
b2	1.100	1.500	-
c	0.450	0.600	-
D	9.70	10.30	-
E	14.70	16.00	-
e	-	-	2.540
L	12.50	13.50	-
L1	2.790	4.500	-
X	6.90	7.10	-
Y	3.000	3.400	-
Y1	3.370	3.900	-
Ø	3.000	3.550	-

All Dimensions in mm

TO220AB Type C (TO220-3(2))



TO220AB Type C			
Dim	Min	Max	Typ
A	-	-	4.500
A2	-	-	2.400
A3	-	-	1.300
b	0.700	0.900	-
b1	-	-	1.270
c	0.400	0.600	-
D	9.800	10.200	-
E	9.000	9.400	-
e	-	-	2.54
H1	6.300	6.700	-
L	12.600	13.600	-
L1	9.600	10.600	-
Y	-	-	11.100
Ø	3.560	3.640	-

All Dimensions in mm

Note: For high voltage applications, the appropriate industry sector guidelines should be considered with regards to voltage spacing between terminals.

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